

DESCRIPTION

The MBB51W is a efficient GaN blue LED with a 430nm peak wavelength, It is encapsulated in a T-1 3/4 standard package with 1 inch lead and clear diffused lens.

FEATURES

High Performance - 700 μ W
 Superior SiC substrate technology
 430nm peak wavelength
 Excellent chip to chip consistency
 High Reliability

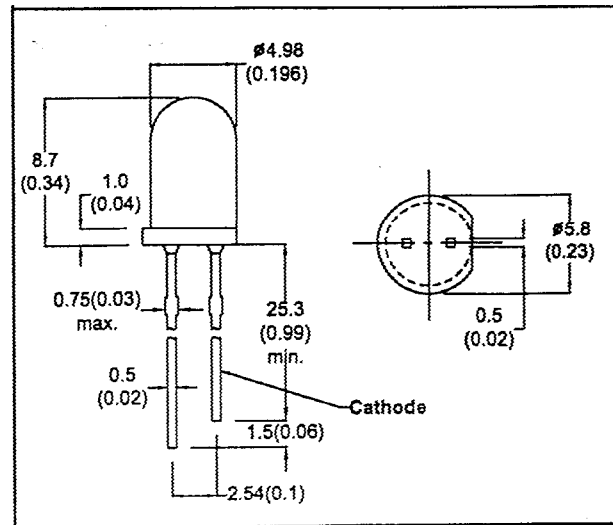
APPLICATIONS

Outdoor Full Color Displays & Moving Message Signs
 Solid State Incandescent Replacement Bulbs
 High Ambient Panel Indicators
 Color Printers and Scanners
 Medical & Analytical Instruments

ABSOLUTE MAXIMUM RATINGS

Power Dissipation @ Ta=25°C	125mW
Forward Current, DC (IF)	25mA
Reverse Voltage	5V
Operating Temperature	-20 to +80°C
Storage Temperature	-30 to +100°C
Lead Temperature	260°C

(Soldering 5 sec., 1/16" form body)



- All dimension in mm(inch)
- No Scale
- Tol. : +/-0.3mm

ELECTRO-OPTICAL CHARACTERISTICS

(Ta=25°C)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNIT	CONDITIONS
Forward Voltage	VF		3.8	5.0	V	IF=20mA
Reverse Current	IR			100	μ A	VR=5V
Luminous Intensity	IV	10	15		mcd	IF=20mA
Peak Wavelength	λ_p		430		nm	IF=20mA
Spectral Line Half Width	$\Delta\lambda$		65		nm	IF=20mA
Viewing Angle	2 θ 1/2		40		degree	IF=20mA

CAUTION

Static electricity does damage these product. Don't apply it to their leadframes.



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